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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	Coldfire V2
Core Size	32-Bit Single-Core
Speed	66MHz
Connectivity	I ² C, SPI, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	43
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16К х 8
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 8x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcf52110cae66

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

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1.1 Block Diagram

Figure 1 shows a top-level block diagram of the device. Package options for this family are described later in this document.



Figure 1. MCF52110 Block Diagram

1.2 Features

1.2.1 Feature Overview

The MCF52110 family includes the following features:



Family Configurations

- Version 2 ColdFire variable-length RISC processor core
 - Static operation
 - 32-bit address and data paths on-chip
 - Up to 80 MHz processor core frequency
 - Up to 40 MHz andoff-chip bus frequency
 - Sixteen general-purpose, 32-bit data and address registers
 - Implements ColdFire ISA_A+. This is ISA_A with extensions to support the user stack pointer register and four new instructions for improved bit processing (ISA_A+)
 - Multiply-Accumulate (MAC) unit with 32-bit accumulator to support $16 \times 16 \rightarrow 32$ or $32 \times 32 \rightarrow 32$ operations
- System debug support
 - Real-time trace for determining dynamic execution path
 - Background debug mode (BDM) for in-circuit debugging (DEBUG_B+)
 - Real-time debug support, with six hardware breakpoints (4 PC, 1 address and 1 data) configurable into a 1- or 2-level trigger
- On-chip memories
 - 16-Kbyte dual-ported SRAM on CPU internal bus, supporting core and DMA access with standby power supply support
 - Up to 128 Kbytes of interleaved flash memory supporting 2-1-1-1 accesses
- Power management
 - Fully static operation with processor sleep and whole chip stop modes
 - Rapid response to interrupts from the low-power sleep mode (wake-up feature)
 - Programmable clock enable/disable for each peripheral when not used (except backup watchdog timer)
 - Software controlled disable of external clock output for low-power consumption
- Three universal asynchronous/synchronous receiver transmitters (UARTs)
 - 16-bit divider for clock generation
 - Interrupt control logic with maskable interrupts
 - DMA support
 - Data formats can be 5, 6, 7 or 8 bits with even, odd, or no parity
 - Up to two stop bits in 1/16 increments
 - Error-detection capabilities
 - Modem support includes request-to-send (RTS) and clear-to-send (CTS) lines for two UARTs
 - Transmit and receive FIFO buffers
- Two I²C modules
 - Interchip bus interface for EEPROMs, LCD controllers, A/D converters, and keypads
 - Fully compatible with industry-standard I²C bus
 - Master and slave modes support multiple masters
 - Automatic interrupt generation with programmable level
- Queued serial peripheral interface (QSPI)
 - Full-duplex, three-wire synchronous transfers
 - Up to four chip selects available
 - Master mode operation only
 - Programmable bit rates up to half the CPU clock frequency
 - Up to 16 pre-programmed transfers
- Fast analog-to-digital converter (ADC)
 - Eight analog input channels
 - 12-bit resolution



1.2.9 QSPI

The queued serial peripheral interface (QSPI) provides a synchronous serial peripheral interface with queued transfer capability. It allows up to 16 transfers to be queued at once, minimizing the need for CPU intervention between transfers.

1.2.10 Fast ADC

The fast ADC consists of an eight-channel input select multiplexer and two independent sample and hold (S/H) circuits feeding separate 12-bit ADCs. The two separate converters store their results in accessible buffers for further processing.

The ADC can be configured to perform a single scan and halt, a scan when triggered, or a programmed scan sequence repeatedly until manually stopped.

The ADC can be configured for sequential or simultaneous conversion. When configured for sequential conversions, up to eight channels can be sampled and stored in any order specified by the channel list register. Both ADCs may be required during a scan, depending on the inputs to be sampled.

During a simultaneous conversion, both S/H circuits are used to capture two different channels at the same time. This configuration requires that a single channel may not be sampled by both S/H circuits simultaneously.

Optional interrupts can be generated at the end of the scan sequence if a channel is out of range (measures below the low threshold limit or above the high threshold limit set in the limit registers) or at several different zero crossing conditions.

1.2.11 DMA Timers (DTIM0–DTIM3)

There are four independent, DMA transfer capable 32-bit timers (DTIM0, DTIM1, DTIM2, and DTIM3) on the device. Each module incorporates a 32-bit timer with a separate register set for configuration and control. The timers can be configured to operate from the system clock or from an external clock source using one of the DTIN*n* signals. If the system clock is selected, it can be divided by 16 or 1. The input clock is further divided by a user-programmable 8-bit prescaler that clocks the actual timer counter register (TCR*n*). Each of these timers can be configured for input capture or reference (output) compare mode. Timer events may optionally cause interrupt requests or DMA transfers.

1.2.12 General Purpose Timer (GPT)

The general purpose timer (GPT) is a four-channel timer module consisting of a 16-bit programmable counter driven by a seven-stage programmable prescaler. Each of the four channels can be configured for input capture or output compare. Additionally, channel three, can be configured as a pulse accumulator.

A timer overflow function allows software to extend the timing capability of the system beyond the 16-bit range of the counter. The input capture and output compare functions allow simultaneous input waveform measurements and output waveform generation. The input capture function can capture the time of a selected transition edge. The output compare function can generate output waveforms and timer software delays. The 16-bit pulse accumulator can operate as a simple event counter or a gated time accumulator.

1.2.13 Periodic Interrupt Timers (PIT0 and PIT1)

The two periodic interrupt timers (PIT0 and PIT1) are 16-bit timers that provide interrupts at regular intervals with minimal processor intervention. Each timer can count down from the value written in its PIT modulus register or it can be a free-running down-counter.



Freescale Semiconductor

MCF52110 ColdFire Microcontroller, Rev. 1

				•	•	•	•	,		
Pin Group	Primary Function	Secondary Function	Tertiary Function	Quaternary Function	Drive Strength / Control ¹	Slew Rate / Control ¹	Pull-up / Pull-down ²	Pin on 100 LQFP	Pin on 81 MAPBGA	Pin on 64 LQFP/QFN
QSPI	QSPI_DIN/ EZPD	SDA1	URXD1	GPIO	PDSR[2]	PSRR[2]	_	16	F3	12
	QSPI_DOUT/ EZPQ	SCL1	UTXD1	GPIO	PDSR[1]	PSRR[1]	_	17	G1	13
	QSPI_CLK/ EZPCK	SCL0	URTS1	GPIO	PDSR[3]	PSRR[3]	pull-up ⁷	18	G2	14
	QSPI_CS3	SYNCA	SYNCB	GPIO	PDSR[7]	PSRR[7]		12	F1	—
	QSPI_CS2	SYNCB	—	GPIO	PDSR[6]	PSRR[6]		13	F2	—
	QSPI_CS1	—	—	GPIO	PDSR[5]	PSRR[5]	—	19	H2	—
	QSPI_CS0	SDA0	UCTS1	GPIO	PDSR[4]	PSRR[4]	pull-up ⁷	20	H1	15
Reset ⁸	RSTI	_		—	N/A	N/A	pull-up ⁸	96	A3	59
	RSTO	—	—	—	high	FAST	—	97	B3	60
Test	TEST	—	—	—	N/A	N/A	pull-down	5	C2	3
Timers, 16-bit	GPT3	_	PWM7	GPIO	PDSR[23]	PSRR[23]	pull-up ⁹	62	D8	43
	GPT2	—	PWM5	GPIO	PDSR[22]	PSRR[22]	pull-up ⁹	61	D9	42
	GPT1	—	PWM3	GPIO	PDSR[21]	PSRR[21]	pull-up ⁹	59	E9	41
	GPT0	_	PWM1	GPIO	PDSR[20]	PSRR[20]	pull-up ⁹	58	F7	40
Timers, 32-bit	DTIN3	DTOUT3	PWM6	GPIO	PDSR[19]	PSRR[19]	—	32	H3	19
	DTIN2	DTOUT2	PWM4	GPIO	PDSR[18]	PSRR[18]	—	31	J3	18
	DTIN1	DTOUT1	PWM2	GPIO	PDSR[17]	PSRR[17]	—	37	G4	23
	DTIN0	DTOUT0	PWM0	GPIO	PDSR[16]	PSRR[16]	—	36	H4	22
UART 0	UCTS0	—	_	GPIO	PDSR[11]	PSRR[11]	—	6	C1	4
	URTS0	—	—	GPIO	PDSR[10]	PSRR[10]	—	9	D3	7
	URXD0	RTC_EXTAL	—	GPIO	PDSR[9]	PSRR[9]	—	7	D1	5
	UTXD0	RTC_XTAL	—	GPIO	PDSR[8]	PSRR[8]	—	8	D2	6
	URXD0 UTXD0	RTC_EXTAL RTC_XTAL		GPIO GPIO	PDSR[9] PDSR[8]	PSRR[9] PSRR[8]		7 8	D1 D2	

Table 3. Pin Functions by Primary and Alternate Purpose (continued)

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Signal Name	Abbreviation	Function	I/O
Development Serial Input	DSI	Development Serial Input - Internally synchronized input that provides data input for the serial communication port to the debug module, after the DSCLK has been seen as high (logic 1).	I
Development Serial Output	DSO	Development Serial Output - Provides serial output communication for debug module responses. DSO is registered internally. The output is delayed from the validation of DSCLK high.	0
Debug Data	DDATA[3:0]	Display captured processor data and breakpoint status. The CLKOUT signal can be used by the development system to know when to sample DDATA[3:0].	0
Processor Status Clock	PSTCLK	Processor Status Clock - Delayed version of the processor clock. Its rising edge appears in the center of valid PST and DDATA output. PSTCLK indicates when the development system should sample PST and DDATA values. If real-time trace is not used, setting CSR[PCD] keeps PSTCLK, and PST and DDATA outputs from toggling without disabling triggers. Non-quiescent operation can be reenabled by clearing CSR[PCD], although the external development systems must resynchronize with the PST and DDATA outputs. PSTCLK starts clocking only when the first non-zero PST value (0xC, 0xD, or 0xF) occurs during system reset exception processing.	0
Processor Status Outputs	PST[3:0]	Indicate core status. Debug mode timing is synchronous with the processor clock; status is unrelated to the current bus transfer. The CLKOUT signal can be used by the development system to know when to sample PST[3:0].	0
All Processor Status Outputs	ALLPST	Logical AND of PST[3:0]. The CLKOUT signal can be used by the development system to know when to sample ALLPST.	0

|--|

1.15 EzPort Signal Descriptions

Table 17 contains a list of EzPort external signals.

Table 17.	EzPort	Signal	Descriptions
-----------	--------	--------	--------------

Signal Name	Abbreviation	Function	I/O
EzPort Clock	EZPCK	Shift clock for EzPort transfers.	Ι
EzPort Chip Select	EZPCS	Chip select for signalling the start and end of serial transfers.	Ι
EzPort Serial Data In	EZPD	EZPD is sampled on the rising edge of EZPCK.	Ι
EzPort Serial Data Out	EZPQ	EZPQ transitions on the falling edge of EZPCK.	0

- ¹ θ_{JA} and Ψ_{jt} parameters are simulated in conformance with EIA/JESD Standard 51-2 for natural convection. Freescale recommends the use of θ_{JA} and power dissipation specifications in the system design to prevent device junction temperatures from exceeding the rated specification. System designers should be aware that device junction temperatures can be significantly influenced by board layout and surrounding devices. Conformance to the device junction temperature specification can be verified by physical measurement in the customer's system using the Ψ_{jt} parameter, the device power dissipation, and the method described in EIA/JESD Standard 51-2.
- ² Per JEDEC JESD51-2 with the single-layer board (JESD51-3) horizontal.
- ³ Per JEDEC JESD51-6 with the board JESD51-7) horizontal.
- ⁴ Thermal resistance between the die and the printed circuit board in conformance with JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- ⁵ Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
- ⁶ Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written in conformance with Psi-JT.

The average chip-junction temperature (T_J) in °C can be obtained from:

$$T_{J} = T_{A} + (P_{D} \times \Theta_{JMA})$$
(1)

Where:

- T_A = ambient temperature, °C
- Θ_{JA} = package thermal resistance, junction-to-ambient, °C/W

 $P_D = P_{INT} + P_{I/O}$

 P_{INT} = chip internal power, $I_{DD} \times V_{DD}$, watts

P_{I/O} = power dissipation on input and output pins — user determined, watts

For most applications $P_{I/O} < P_{INT}$ and can be ignored. An approximate relationship between P_D and T_J (if $P_{I/O}$ is neglected) is:

$$P_{\rm D} = K \div (T_{\rm J} + 273^{\circ}C)$$
 (2)

Solving equations 1 and 2 for K gives:

$$K = P_D \times (T_A + 273 \ ^\circ C) + \Theta_{JMA} \times P_D^2 \ (3)$$

where K is a constant pertaining to the particular part. K can be determined from equation (3) by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and T_J can be obtained by solving equations (1) and (2) iteratively for any value of T_A .

2.4 Flash Memory Characteristics

The flash memory characteristics are shown in Table 23 and Table 24.

Table 23. SGFM Flash Program and Erase Characteristics

(V_{DD} = 3.0 to 3.6 V)

Parameter	Symbol	Min	Тур	Мах	Unit
System clock (read only)	f _{sys(R)}	0	—	50–80 ¹	MHz
System clock (program/erase) ²	f _{sys(P/E)}	0.15	—	102.4	MHz

¹ Depending on packaging; see the orderable part number summary.

² Refer to the flash memory section for more information



Table 28. Oscillator and PLL Electrical Specifications (continued)

 $(V_{DD} \text{ and } V_{DDPLL} = 2.7 \text{ to } 3.6 \text{ V}, V_{SS} = V_{SSPLL} = 0 \text{ V})$

Characteristic	Symbol	Min	Мах	Unit
Frequency un-LOCK range	f _{UL}	-1.5	1.5	% f _{ref}
Frequency LOCK range	f _{LCK}	-0.75	0.75	% f _{ref}
 CLKOUT period jitter ^{4, 5, 10, 11}, measured at f_{SYS} Max Peak-to-peak (clock edge to clock edge) Long term (averaged over 2 ms interval) 	C _{jitter}		10 .01	% f _{sys}
On-chip oscillator frequency	f _{oco}	7.84	8.16	MHz

¹ In external clock mode, it is possible to run the chip directly from an external clock source without enabling the PLL.

- ² This value has been updated.
- ³ All internal registers retain data at 0 Hz.
- ⁴ Depending on packaging; see the orderable part number summary.
- ⁵ Loss of Reference Frequency is the reference frequency detected internally, which transitions the PLL into self clocked mode.
- ⁶ Self clocked mode frequency is the frequency at which the PLL operates when the reference frequency falls below f_{LOR} with default MFD/RFD settings.
- ⁷ This parameter is characterized before qualification rather than 100% tested.
- ⁸ Proper PC board layout procedures must be followed to achieve specifications.
- ⁹ This specification applies to the period required for the PLL to relock after changing the MFD frequency control bits in the synthesizer control register (SYNCR).
- ¹⁰ Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{sys}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V_{DDPLL} and V_{SSPLL} and variation in crystal oscillator frequency increase the C_{jitter} percentage for a given interval.
- ¹¹ Based on slow system clock of 40 MHz measured at f_{svs} max.

2.9 General Purpose I/O Timing

GPIO can be configured for certain pins of the QSPI, DDR Control, timer, UART, and Interrupt interfaces. When in GPIO mode, the timing specification for these pins is given in Table 29 and Figure 5.

The GPIO timing is met under the following load test conditions:

- 50 pF / 50 Ω for high drive
- $25 \text{ pF} / 25 \Omega$ for low drive

Table 29. GPIO Timing

NUM	Characteristic	Symbol	Min	Мах	Unit
G1	CLKOUT High to GPIO Output Valid	t _{CHPOV}		10	ns
G2	CLKOUT High to GPIO Output Invalid	t _{CHPOI}	1.5	—	ns
G3	GPIO Input Valid to CLKOUT High	t _{PVCH}	9	—	ns
G4	CLKOUT High to GPIO Input Invalid	t _{CHPI}	1.5	—	ns





Figure 5. GPIO Timing

2.10 Reset Timing

Table 30. Reset and Configuration Override Timing

$(V_{DD} = 3.0 \text{ to } 3.6 \text{ V}, V_{SS} = 0.0 \text{ to } 3.6 \text{ V})$)V,I,	$= I_{L}$	to I _H)'
--	-------	-----------	----------------------

NUM	Characteristic	Symbol	Min	Мах	Unit
R1	RSTI input valid to CLKOUT High	t _{RVCH}	9	—	ns
R2	CLKOUT High to RSTI Input invalid	t _{CHRI}	1.5	—	ns
R3	RSTI input valid time ²	t _{RIVT}	5	—	t _{CYC}
R4	CLKOUT High to RSTO Valid	t _{CHROV}	—	10	ns

¹ All AC timing is shown with respect to 50% V_{DD} levels unless otherwise noted.

² During low power STOP, the synchronizers for the RSTI input are bypassed and RSTI is asserted asynchronously to the system. Thus, RSTI must be held a minimum of 100 ns.



Figure 6. RSTI and Configuration Override Timing

2.11 I²C Input/Output Timing Specifications

Table 31 lists specifications for the I^2C input timing parameters shown in Figure 7.

NP

Figure 7 shows timing for the values in Table 31 and Table 32.



Figure 7. I²C Input/Output Timings

2.12 Analog-to-Digital Converter (ADC) Parameters

Table 33 lists specifications for the analog-to-digital converter.

Table	33.	ADC	Param	eters ¹
-------	-----	-----	-------	--------------------

Name	Characteristic	Min	Typical	Мах	Unit
V _{REFL}	Low reference voltage	V _{SSA}	—	V _{SSA}	V
V _{REFH}	High reference voltage	V _{DDA}	—	V _{DDA}	V
V _{DDA}	ADC analog supply voltage	3.0	3.3	3.6	V
V _{ADIN}	Input voltages	V _{REFL}	—	V _{REFH}	V
RES	Resolution	12	—	12	Bits
INL	Integral non-linearity (full input signal range) ²	—	±2.5	±3	LSB ³
INL	Integral non-linearity (10% to 90% input signal range) ⁴	—	±2.5	±3	LSB
DNL	Differential non-linearity	—	-1 < DNL < +1	<+1	LSB
Monotonicity			GUARAN	ITEED	•
f _{ADIC}	ADC internal clock	0.1	—	5.0	MHz
R _{AD}	Conversion range	V _{REFL}	—	V _{REFH}	V
t _{ADPU}	ADC power-up time ⁵	—	6	13	t _{AIC} cycles ⁶
t _{REC}	Recovery from auto standby	—	0	1	t _{AIC} cycles
t _{ADC}	Conversion time	—	6	—	t _{AIC} cycles
t _{ADS}	Sample time		1	_	t _{AIC} cycles
C _{ADI}	Input capacitance	—	See Figure 8	—	pF
X _{IN}	Input impedance	—	See Figure 8	—	W
I _{ADI}	Input injection current ⁷ , per pin	—	—	3	mA
I _{VREFH}	V _{REFH} current	—	0	—	mA
V _{OFFSET}	Offset voltage internal reference	—	±8	±15	mV
E _{GAIN}	Gain error (transfer path)	.99	1	1.01	—
V _{OFFSET}	Offset voltage external reference	—	±3	9	mV
SNR	Signal-to-noise ratio	—	62 to 66	—	dB



Num	Characteristics ¹		Min	Max	Unit
J1	TCLK frequency of operation	f _{JCYC}	DC	1/4	f _{sys/2}
J2	TCLK cycle period	t _{JCYC}	$4 \times t_{CYC}$	—	ns
J3	TCLK clock pulse width	t _{JCW}	26	—	ns
J4	TCLK rise and fall times	t _{JCRF}	0	3	ns
J5	Boundary scan input data setup time to TCLK rise	t _{BSDST}	4	—	ns
J6	Boundary scan input data hold time after TCLK rise	t _{BSDHT}	26	—	ns
J7	TCLK low to boundary scan output data valid	t _{BSDV}	0	33	ns
J8	TCLK low to boundary scan output high Z	t _{BSDZ}	0	33	ns
J9	TMS, TDI input data setup time to TCLK rise	t _{TAPBST}	4	—	ns
J10	TMS, TDI Input data hold time after TCLK rise	t _{TAPBHT}	10	—	ns
J11	TCLK low to TDO data valid	t _{TDODV}	0	26	ns
J12	TCLK low to TDO high Z	t _{TDODZ}	0	8	ns
J13	TRST assert time	t _{TRSTAT}	100	_	ns
J14	TRST setup time (negation) to TCLK high	t _{TRSTST}	10	_	ns

Table 36. JTAG and Boundary Scan Timing

¹ JTAG_EN is expected to be a static signal. Hence, it is not associated with any timing.



Figure 10. Test Clock Input Timing



Mechanical Outline Drawings

NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.
- 4. DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.
- 5. THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 mm AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 mm.
- 6. THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY SIZE DIMENSION INCLUDING MOLD MISMATCH.
- / EXACT SHAPE OF EACH CORNER IS OPTIONAL.
- AND 0.25 mm FROM THE LEAD TIP.

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TITLE: 64LD LQFP,		DOCUMENT NO	: 98ASS23234₩	REV: D
10 X 10 X 1.4 PKG,		CASE NUMBER	2: 840F-02	06 APR 2005
0.5 PITCH, CASE OU	TLINE	STANDARD: JE	DEC MS-026 BCD	



3.2 64 QFN Package



Mechanical Outline Drawings



Mechanical Outline Drawings

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					DOCUMENT NO: 98ASA10690D		
	Treesca semicone	71C ductor	REVISION HISTORY		PAGE:	174	0
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LTR	ORIGINATOR		REVIS	SIONS	•	DRAFTER	DATE
0	ERIC TRIPLETT	RELEASED FO	R PRODUCTION			TAYLOR LIU	27JUL2005
TITLE:	THERMALLY	ENHANCE	ED QUAD	CASE NUMBER: 1	740-01		
FLA	AT NON-LEA TERMINIAL O	DED PAC	KAGE (QFN)	STANDARD: JEDEC MO-220 VMMD-3			
04	64 IERMINAL, 0.5 PITCH (9 X 9 X 1)		PACKAGE CODE:	6200	SHEET:	4 OF 4	



3.3 81 MAPBGA Package



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TITLE: PBGA, LOW	PROFILE	_ _,	DOCUMENT NO	: 98ASA10670D	REV: O
81 I/O, 10 X 10 PKG,		CASE NUMBER	: 1662–01	04 FEB 2005	
1 MM PITCH	H (MAP))	STANDARD: NO	N-JEDEC	



Mechanical Outline Drawings

NOTES:

- 1. ALL DIMENSIONS IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- /3, maximum solder ball diameter measured parallel to datum a.



5. PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

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TITLE: PBGA, LOW PROFIL	E, DOCU	MENT NO: 98ASA10670D	REV: O
81 I/O, 10 X 10 PI	KG, CASE	NUMBER: 1662-01	04 FEB 2005
1 MM PITCH (MAF) STANI	DARD: NON-JEDEC	



3.4 100-pin LQFP Package



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TITLE: 100 LEAD LQFP 14 X 14, 0.5 PITCH, 1.4 THICK		DOCUMENT NO): 98ASS23308W	REV: G
		CASE NUMBER	2: 983–03	07 APR 2005
		STANDARD: NO	DN-JEDEC	





4 Revision History

Table 38. Revision History

Revision	Description
0	Initial public release.
1	 Updated Clock generation features Changed crystal frequency range maximum to 25 MHz Updated Table: Clocking Modes and added appropriate footnote In Table: CLock Source Electrical Specifications, updated the following values: fcrystal, fext, fref_pll, EXTAL input high voltage (External reference)



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Japan:

Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064 Japan 0120 191014 or +81 3 5437 9125 support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor China Ltd. Exchange Building 23F No. 118 Jianguo Road Chaoyang District Beijing 100022 China +86 10 5879 8000 support.asia@freescale.com

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